

# Octal 13-Bit, Parallel Input, Voltage-Output DAC

AD7839

**FEATURES** 

Eight 13-Bit DACs in One Package Voltage Outputs Offset Adjust for Each DAC Pair Reference Range of ±5 V Maximum Output Voltage Range of ±10 V Clear Function to User-Defined Voltage 44-Lead MQFP Package

APPLICATIONS
Automatic Test Equipment
Process Control
General Purpose Instrumentation

# **GENERAL DESCRIPTION**

The AD7839 contains eight 13-bit DACs on one monolithic chip. It has output voltages with a full-scale range of  $\pm 10$  V from reference voltages of  $\pm 5$  V.

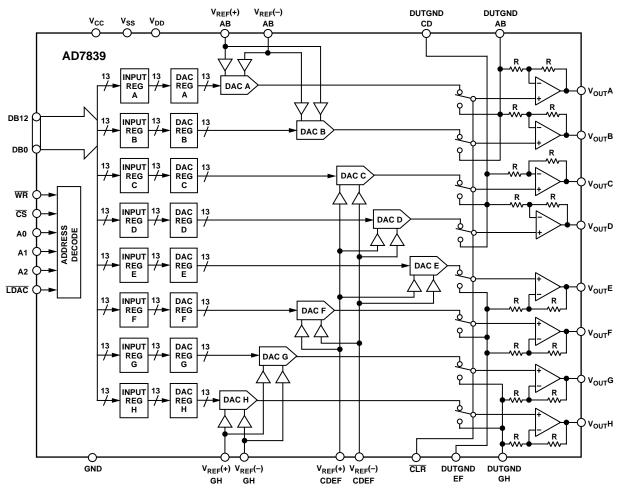
The AD7839 accepts 13-bit parallel loaded data from the external bus into one of the input registers under the control of the  $\overline{WR}$ ,  $\overline{CS}$  and DAC channel address pins, A0–A2.

The DAC outputs are updated on reception of new data into the DAC registers. All the outputs may be updated simultaneously by taking the  $\overline{\text{LDAC}}$  input low.

Each DAC output is buffered with a gain-of-two amplifier into which an external DAC offset voltage can be inserted via the DUTGNDx pins.

The AD7839 is available in a 44-lead MQFP package.

## FUNCTIONAL BLOCK DIAGRAM



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# $\label{eq:continuous} \textbf{AD7839-SPECIFICATIONS} \begin{subarray}{l} (V_{CC} = +5 \text{ V} \pm 5\%; V_{DD} = +15 \text{ V} \pm 5\%; V_{SS} = -15 \text{ V} \pm 5\%; \text{GND} = \text{DUTGND} = 0 \text{ V}; \\ R_L = 5 \text{ k} \Omega \text{ and } C_L = 50 \text{ pF to GND, } T_A{}^1 = T_{MIN} \text{ to } T_{MAX} \text{, unless otherwise noted.} \end{subarray}$

Parameter	A Version	Units	Test Conditions/Comments
ACCURACY			
Resolution	13	Bits	
Relative Accuracy	±2	LSB max	Typically ±0.5 LSB
Differential Nonlinearity	±0.9	LSB max	Guaranteed Monotonic Over Temperature
Zero-Scale Error	±4	LSB max	$V_{REF}(+) = +5 \text{ V}, V_{REF}(-) = -5 \text{ V}.$ Typically within $\pm 1 \text{ LSE}$
Full-Scale Error	±4	LSB max	$V_{REF}(+) = +5 \text{ V}, V_{REF}(-) = -5 \text{ V}.$ Typically within $\pm 1 \text{ LSE}$
Gain Error	±1	LSB typ	$V_{REF}(+) = +5 \text{ V}, V_{REF}(-) = -5 \text{ V}$
Gain Temperature Coefficient <sup>2</sup>	0.5	ppm FSR/°C typ	Idi ( ) Idi ( )
•	10	ppm FSR/°C max	
DC Crosstalk <sup>2</sup>	120	μV max	See Terminology. Typically 75 μV
REFERENCE INPUTS <sup>2</sup>			
DC Input Impedance	100	MΩ typ	
Input Current	±1	μA max	Per Input. Typically ±0.03 μA
$V_{REF}(+)$ Range	0/+5	V min/max	Ter input. Typicany 20.05 par
$V_{REF}(-)$ Range	-5/0	V min/max	
$[V_{REF}(+) - V_{REF}(-)]$	+2/+10	V min/max	For Specified Performance. Can Go as Low as 0 V, but
['REF(') 'REF()]	12/110	V IIIII/IIIIX	Performance Not Guaranteed
DUTGND INPUTS <sup>2</sup>			
DC Input Impedance	60	kΩ typ	
Max Input Current	±0.3	mA typ	Per Input
Input Range	-2/+2	V min/max	_
OUTPUT CHARACTERISTICS <sup>2</sup>			
Output Voltage Swing	±10	V min	$2 \times (V_{REF}(-) + [V_{REF}(+) - V_{REF}(-)] \times D) - V_{DUTGND}$
Short Circuit Current	15	mA max	- CONDICTED CONDICTED
Resistive Load	5	kΩ min	To 0 V
Capacitive Load	50	pF max	To 0 V
DC Output Impedance	0.5	Ω max	
DIGITAL INPUTS <sup>2</sup>			
V <sub>INH</sub> , Input High Voltage	2.4	V min	
V <sub>INL</sub> , Input Low Voltage	0.8	V max	
I <sub>INH</sub> , Input Current			Total for All Pins
@ +25°C	1	μA max	
$T_{MIN}$ to $T_{MAX}$	±10	μA max	
C <sub>IN</sub> , Input Capacitance	10	pF max	
POWER REQUIREMENTS <sup>3</sup>			
$V_{CC}$	+4.75/+5.25	V min/max	For Specified Performance
$V_{ m DD}$	+14.25/+15.75	V min/max	For Specified Performance
$V_{SS}$	-14.25/-15.75	V min/max	For Specified Performance
Power Supply Sensitivity <sup>2</sup>			•
$\Delta$ Full Scale/ $\Delta$ V <sub>DD</sub>	90	dB typ	
$\Delta$ Full Scale/ $\Delta$ V <sub>SS</sub>	90	dB typ	
$ m I_{CC}$	0.5	mA max	$V_{INH} = V_{CC}$ , $V_{INL} = GND$ . Dynamic Current
$I_{\mathrm{DD}}$	10	mA max	Outputs Unloaded. Typically 8 mA
$I_{SS}$	10	mA max	Outputs Unloaded. Typically 8 mA

## NOTES

Specifications subject to change without notice.

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 $<sup>^{1}</sup>Temperature$  range for A Version:  $-40\,^{\circ}C$  to +85 $^{\circ}C$ 

<sup>&</sup>lt;sup>2</sup>Guaranteed by characterization. Not production tested.

 $<sup>^3</sup>$ The AD7839 is functional with power supplies of  $\pm 12~V \pm 10\%$  with reduced output range. At 12 V it is recommended to restrict reference range to  $\pm 4~V$  due to output amplifier headroom limitations

# AC PERFORMANCE CHARACTERISTICS (These characteristics are included for Design Guidance and are not subject to production testing.)

Parameter	A	Units	Test Conditions/Comments
DYNAMIC PERFORMANCE			
Output Voltage Settling Time	30	μs typ	Full-Scale Change to $\pm 1/2$ LSB. DAC Latch Contents Alternately
	40	μs max	Loaded with All 0s and All 1s
Slew Rate	0.7	V/μs typ	
Digital-to-Analog Glitch Impulse	230	nV-s typ	Measured with $V_{REF}(+) = +5 \text{ V}$ , $V_{REF}(-) = -5 \text{ V}$ . DAC Latch
			Alternately Loaded with 0FFF Hex and 1000 Hex. Not Dependent
			on Load Conditions
Channel-to-Channel Isolation	99	dB typ	See Terminology
DAC-to-DAC Crosstalk	40	nV-s typ	See Terminology
Digital Crosstalk	0.2	nV-s typ	Feedthrough to DAC Output Under Test Due to Change in Digital
			Input Code to Another Converter
Digital Feedthrough	0.1	nV-s typ	Effect of Input Bus Activity on DAC Output Under Test
Output Noise Spectral Density		"	
@ 1 kHz	200	nV/√ <del>Hz</del> typ	All 1s Loaded to DAC. $V_{REF}(+) = V_{REF}(-) = 0 \text{ V}$

Specifications subject to change without notice.

# 

Parameter	Limit at T <sub>MIN</sub> , T <sub>MAX</sub>	Units	Description
$\overline{t_1}$	15	ns min	Address to WR Setup Time
$t_2$	0	ns min	Address to $\overline{\mathrm{WR}}$ Hold Time
$t_3$	50	ns min	CS Pulsewidth Low
$t_4$	50	ns min	WR Pulsewidth Low
t <sub>5</sub>	0	ns min	$\overline{\text{CS}}$ to $\overline{\text{WR}}$ Setup Time
$t_6$	0	ns min	$\overline{\mathrm{WR}}$ to $\overline{\mathrm{CS}}$ Hold Time
t <sub>7</sub>	20	ns min	Data Setup Time
t <sub>8</sub>	0	ns min	Data Hold Time
t <sub>9</sub>	30	μs typ	Settling Time
t <sub>10</sub>	300	ns max	CLR Pulse Activation Time
t <sub>11</sub>	50	ns min	LDAC Pulsewidth Low

# NOTES

 $^{1}$ All input signals are specified with tr = tf = 5 ns (10% to 90% of 5 V) and timed from a voltage level of 1.6 V.

Specifications subject to change without notice.

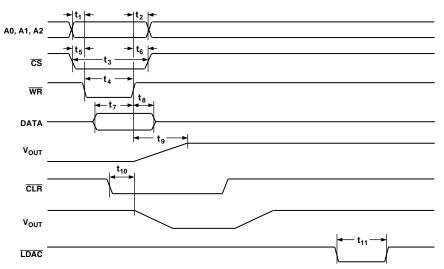


Figure 1. Timing Diagram

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<sup>&</sup>lt;sup>2</sup>Rise and fall times should be no longer than 50 ns.

# ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>

$(T_A = +25^{\circ}C \text{ unless otherwise noted})$
$V_{CC}$ to $GND^3$ $\ \ldots \ -0.3\ V,$ +7 V or $V_{DD}$ + 0.3 V
(Whichever Is Lower)
$V_{DD}$ to GND0.3 V, +17 V
$V_{SS}$ to GND
Digital Inputs to GND $\dots -0.3 \text{ V}, \text{V}_{\text{CC}} + 0.3 \text{ V}$
$V_{REF}(\mbox{+})$ to $V_{REF}(\mbox{-})$ $$
$V_{REF}(+)$ to GND $V_{SS}$ – 0.3 V, $V_{DD}$ + 0.3 V
$V_{REF}(-)$ to GND $V_{SS}$ – 0.3 V, $V_{DD}$ + 0.3 V
DUTGND to GND $V_{SS}$ – 0.3 V, $V_{DD}$ + 0.3 V
$V_{OUT}\left(A\text{H}\right)$ to GND $\ldots$
Operating Temperature Range
Industrial (A Version)40°C to +85°C
Storage Temperature Range65°C to +150°C
Junction Temperature ( $T_J$ max) +150°C
MQFP Package
Power Dissipation $(T_J \max - T_A)/\theta_{JA}$
$\theta_{JA}$ Thermal Impedance 95°C/W

Lead Temperature, Soldering	
Vapor Phase (60 sec)	+215°C
Infrared (15 sec)	+220°C
ESD Rating	>4000 V

## NOTES

<sup>1</sup>Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

 $<sup>^3</sup>$ V $_{CC}$  must not exceed  $^3$ V $_{DD}$  by more than 0.3 V. If it is possible for this to happen during power supply sequencing, the following diode protection scheme will ensure protection.

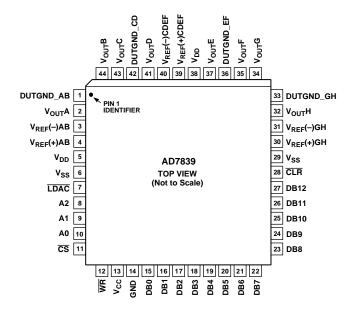


# **ORDERING GUIDE**

Model	Temperature Range	Linearity Error (LSBs)	DNL (LSBs)	Package Option*
AD7839AS	−40°C to +85°C	±2	±1	S-44

<sup>\*</sup>S = Plastic Quad Flatpack (MQFP).

# PIN CONFIGURATION



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<sup>&</sup>lt;sup>2</sup>Transient currents of up to 100 mA will not cause SCR latch-up.

# PIN FUNCTION DESCRIPTIONS

Pin No.	Mnemonic	Description	
1	DUTGND_AB	Device Sense Ground for DACs A and B. $V_{\rm OUT}A$ and $V_{\rm OUT}B$ are referenced to the voltage applied to this pin.	
2, 44, 43, 41, 37, 35, 34, 32	$V_{OUT}A \dots V_{OUT}H$	DAC Outputs.	
4, 3	$V_{REF}(+)AB, V_{REF}(-)AB$	Reference Inputs for DACs A and B. These reference voltages are referred to GND.	
5	$V_{\mathrm{DD}}$	Positive Analog Power Supply; +15 V ± 5%.	
6	$V_{SS}$	Negative Analog Power Supply; $-15 \text{ V} \pm 5\%$ .	
7	LDAC	Load DAC Logic Input (active low). When this logic input is taken low the contents of the input registers are transferred to their respective DAC registers. $\overline{\text{LDAC}}$ can be tied permanently low enabling the outputs to be updated on the rising edge of $\overline{\text{WR}}$ .	
10, 9, 8	A0, A1, A2	Address inputs. A0, A1 and A2 are decoded to select one of the eight input registers for a data transfer.	
11	CS	Level-Triggered Chip Select Input (active low). The device is selected when this input is low.	
12	WR	Level-Triggered Write Input (active low), used in conjunction with $\overline{CS}$ to write data to the AD7839 input registers. Data is latched into the selected input register on the rising edge of $\overline{WR}$ .	
13	$V_{CC}$	Logic Power Supply; +5 V ± 5%.	
14	GND	Ground.	
15–27	DB0 DB12	Parallel Data Inputs. The AD7839 can accept a straight 13-bit parallel word on DB0 to DB12 where DB12 is the MSB and DB0 is the LSB.	
28	CLR	Asynchronous Clear Input (level sensitive, active low). When this input is low, all analog outputs are switched to the externally set potential on the relevant DUTGND pin. The contents of input registers and DAC registers A to H are not affected when the CLR pin is take low. When CLR is brought back high, the DAC outputs revert to their original outputs as determined by the data in their DAC registers.	
30, 31	$V_{REF}(+)GH, V_{REF}(-)GH$	Reference Inputs for DACs G and H. These reference voltages are referred to GND.	
33	DUTGND_GH	Device Sense Ground for DACs G and H. V <sub>OUT</sub> G and V <sub>OUT</sub> H are referenced to the voltage applied to this pin.	
36	DUTGND_EF	Device Sense Ground for DACs E and F. V <sub>OUT</sub> E and V <sub>OUT</sub> F are referenced to the voltage applied to this pin.	
39	V <sub>REF</sub> (+)CDEF	Reference Inputs for DACs C, D, E and F. These reference voltages are referred to GND.	
40	V <sub>REF</sub> (-)CDEF		
42	DUTGND_CD	Device Sense Ground for DACs C and D. $V_{OUT}C$ and $V_{OUT}D$ are referenced to the voltage applied to this pin.	

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## **TERMINOLOGY**

### Relative Accuracy

Relative accuracy or endpoint linearity is a measure of the maximum deviation from a straight line passing through the endpoints of the DAC transfer function. It is measured after adjusting for zero error and full-scale error and is normally expressed in Least Significant Bits.

# **Differential Nonlinearity**

Differential nonlinearity is the difference between the measured change and the ideal 1 LSB change between any two adjacent codes. A specified differential nonlinearity of 1 LSB maximum ensures monotonicity.

#### DC Crosstalk

Although the common input reference voltage signals are internally buffered, small IR drops in the individual DAC reference inputs across the die can mean that an update to one channel can produce a dc output change in one or another of the channel outputs.

The eight DAC outputs are buffered by op amps that share common  $V_{\rm DD}$  and  $V_{\rm SS}$  power supplies. If the dc load current changes in one channel (due to an update), this can result in a further dc change in one or another of the channel outputs. This effect is most obvious at high load currents and reduces as the load currents are reduced. With high impedance loads the effect is virtually unmeasurable.

# **Output Voltage Settling Time**

This is the amount of time it takes for the output to settle to a specified level for a full-scale input change.

# Digital-to-Analog Glitch Impulse

This is the amount of charge injected into the analog output when the inputs change state. It is specified as the area of the glitch in nV-secs. It is measured with  $V_{REF}(+) = +5$  V and  $V_{REF}(-) = -5$  V and the digital inputs toggled between 0FFFH and 1000H.

# **Channel-to-Channel Isolation**

Channel-to-channel isolation refers to the proportion of input signal from one DAC's reference input that appears at the output of another DAC. It is expressed in dBs.

# **DAC-to-DAC Crosstalk**

DAC-to-DAC crosstalk is defined as the glitch impulse that appears at the output of one converter due to both the digital change and subsequent analog O/P change at another converter. It is specified in nV-secs.

# **Digital Crosstalk**

The glitch impulse transferred to the output of one converter due to a change in digital input code to the other converter is defined as the digital crosstalk and is specified in nV-secs.

# Digital Feedthrough

When the device is not selected, high frequency logic activity on the device's digital inputs can be capacitively coupled both across and through the device to show up as noise on the  $V_{\rm OUT}$  pins. This noise is digital feedthrough.

# DC Output Impedance

This is the effective output source resistance. It is dominated by package lead resistance.

### **Full-Scale Error**

This is the error in DAC output voltage when all 1s are loaded into the DAC latch. Ideally the output voltage, with all 1s loaded into the DAC latch, should be 2  $V_{REF}(+)$  – 1 LSB.

# **Zero-Scale Error**

Zero-scale error is the error in the DAC output voltage when all 0s are loaded into the DAC latch. Ideally the output voltage, with all 0s in the DAC latch should be equal to  $2\ V_{REF}(-)$ . Zero-scale error is mainly due to offsets in the output amplifier.

#### Gain Error

Gain Error is defined as (Full-Scale Error) – (Zero-Scale Error).

# GENERAL DESCRIPTION

# DAC Architecture—General

Each channel consists of a straight 13-bit R-2R voltage-mode DAC. The full-scale output voltage range is equal to twice the reference span of  $V_{REF}(+) - V_{REF}(-)$ . The DAC coding is straight binary; all 0s produces an output of 2  $V_{REF}(-)$ ; all 1s produces an output of 2  $V_{REF}(+) - 1$  LSB.

The analog output voltage of each DAC channel reflects the contents of its own DAC register. Data is transferred from the external bus to the input register of each DAC on a per channel basis.

Bringing the  $\overline{CLR}$  line low switches all the signal outputs,  $V_{OUT}A$  to  $V_{OUT}H$ , to the voltage level on the DUTGND pin. When the  $\overline{CLR}$  signal is brought back high, the output voltages from the DACs will reflect the data stored in the relevant DAC registers.

# Data Loading to the AD7839

Data is loaded into the AD7839 in straight parallel 13-bit wide words.

The DAC output voltages,  $V_{OUT}A - V_{OUT}H$  are updated to reflect new data in the DAC registers.

The actual input register being written to is determined by the logic levels present on the device's address lines, as shown in Table I.

Table I. Address Line Truth Table

A2	A1	A0	DAC Selected
0	0	0	INPUT REG A (DAC A)
0	0	1	INPUT REG B (DAC B)
0	1	0	INPUT REG C (DAC C)
0	1	1	INPUT REG D (DAC D)
1	0	0	INPUT REG E (DAC E)
1	0	1	INPUT REG F (DAC F)
1	1	0	INPUT REG G (DAC G)
1	1	1	INPUT REG H (DAC H)

# **Typical Performance Characteristics—AD7839**

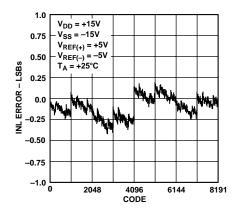


Figure 2. Typical INL Plot

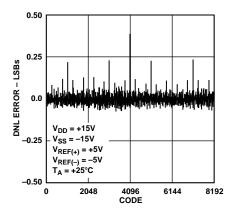


Figure 3. Typical DNL Plot

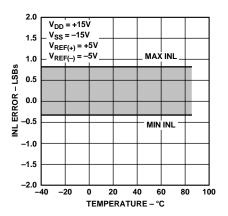


Figure 4. Typical INL Error vs. Temperature

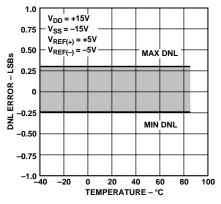


Figure 5. Typical DNL Error vs. Temperature

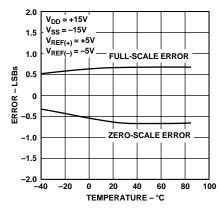


Figure 6. Zero-Scale and Full-Scale Error vs. Temperature

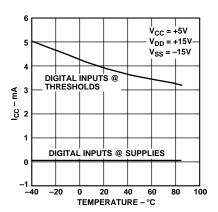


Figure 7. I<sub>CC</sub> vs. Temperature

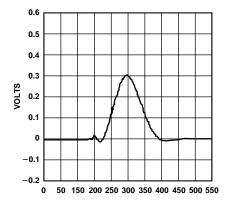


Figure 8. Typical Digital-to-Analog Glitch Impulse

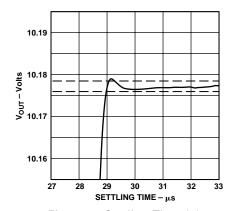


Figure 9. Settling Time (+)

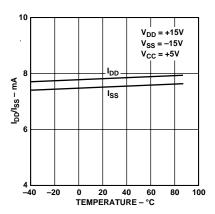
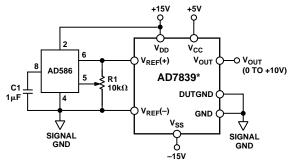


Figure 10. I<sub>DD</sub>, I<sub>SS</sub> vs. Temperature

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# **Unipolar Configuration**

Figure 11 shows the AD7839 in the unipolar binary circuit configuration. The  $V_{REF}(+)$  input of the DAC is driven by the AD586, a +5 V reference.  $V_{REF}(-)$  is tied to ground. Table II gives the code table for unipolar operation of the AD7839. Other suitable references include the REF02, a precision +5 V reference, and the REF195, a low dropout, micropower precision +5 V reference.



\*ADDITIONAL PINS OMITTED FOR CLARITY

Figure 11. Unipolar +10 V Operation

Offset and gain may be adjusted in Figure 11 as follows: To adjust offset, disconnect the  $V_{REF}(-)$  input from 0 V, load the DAC with all 0s and adjust the  $V_{REF}(-)$  voltage until  $V_{OUT}$  = 0 V. For gain adjustment, the AD7839 should be loaded with all 1s and R1 adjusted until  $V_{OUT}$  = 2  $V_{REF}(+)$  – 1 LSB = 10 V(8191/8192) = 9.99878 V.

Many circuits will not require these offset and gain adjustments. In these circuits R1 can be omitted. Pin 5 of the AD586 may be left open circuit and Pin 2 ( $V_{\rm REF}(-)$ ) of the AD7839 tied to 0 V.

Table II. Code Table for Unipolar Operation

Bina MSB	ry Numbe	er in DA	Analog Output (V <sub>OUT</sub> )	
1	1111	1111	1111	2 V <sub>REF</sub> (8191/8192) V
1	0000	0000	0000	2 V <sub>REF</sub> (4096/8192) V
0	1111	1111	1111	2 V <sub>REF</sub> (4095/8192) V
0	0000	0000	0001	2 V <sub>REF</sub> (1/8192) V
0	0000	0000	0000	0 V

## NOTES

 $V_{REF} = V_{REF}(+); V_{REF}(-) = 0 \text{ V for unipolar operation.}$ For  $V_{REF}(+) = +5 \text{ V}, 1 \text{ LSB} = +10 \text{ V}/2^{13} = +10 \text{ V}/8192 = 1.22 \text{ mV}.$ 

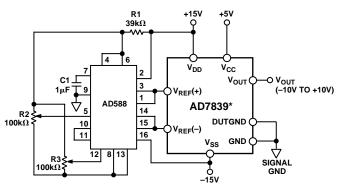
# **Bipolar Configuration**

Figure 12 shows the AD7839 set up for  $\pm 10$  V operation. The AD588 provides precision  $\pm 5$  V tracking outputs that are fed to the  $V_{REF}(+)$  and  $V_{REF}(-)$  inputs of the AD7839. The code table for bipolar operation of the AD7839 is shown in Table III.

In Figure 12, full-scale and bipolar zero adjustments are provided by varying the gain and balance on the AD588. R2 varies the gain on the AD588 while R3 adjusts the offset of both the +5 V and -5 V outputs together with respect to ground.

For bipolar-zero adjustment, the DAC is loaded with 1000 . . . 0000 and R3 is adjusted until  $V_{OUT}$  = 0 V. Full scale is adjusted by loading the DAC with all 1s and adjusting R2 until  $V_{OUT}$  = 10(4095/4096) V = 9.997559 V.

When bipolar-zero and full-scale adjustment are not needed, R2 and R3 can be omitted. Pin 12 on the AD588 should be connected to Pin 11 and Pin 5 should be left floating.



\*ADDITIONAL PINS OMITTED FOR CLARITY Figure 12. Bipolar  $\pm$  10 V Operation

Table III. Code Table for Bipolar Operation

Binary Number in DAC Register MSB LSB				Analog Output $(V_{OUT})$
1	1111	1111	1111	$2[V_{REF}(-) + V_{REF}(8191/8192)] V$
1	0000	0000	0001	$2[V_{REF}(-) + V_{REF}(4097/8192)] V$
1	0000	0000	0000	$2[V_{REF}(-) + V_{REF} (4096/8192)] V$
0	1111	1111	1111	$2[V_{REF}(-) + V_{REF} (4095/8192)] V$
0	0000	0000	0001	$2[V_{REF}(-) + V_{REF}(1/8192)] V$
0	0000	0000	0000	2[V <sub>REF</sub> (-)] V

## NOTES

 $V_{REF} = (V_{REF}(+) - V_{REF}(-)).$ 

For  $V_{REF}(+) = +5 V$ , and  $V_{REF}(-) = -5 V$ ,  $V_{REF} = 10 V$ , 1 LSB = 2  $V_{REF} V/2^{13} = 20 V/8192 = 2.44 mV$ .

## CONTROLLED POWER-ON OF THE OUTPUT STAGE

A block diagram of the output stage of the AD7839 is shown in Figure 13. It is capable of driving a load of 5 k $\Omega$  in parallel with 50 pF.  $G_1$  to  $G_6$  are transmission gates used to control the power on voltage present at  $V_{\rm OUT}$ . On power up  $G_1$  and  $G_2$  are also used in conjunction with the  $\overline{\rm CLR}$  input to set  $V_{\rm OUT}$  to the user defined voltage present at the DUTGND pin. When  $\overline{\rm CLR}$  is taken back high, the DAC outputs reflect the data in the DAC registers.

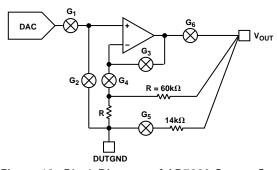


Figure 13. Block Diagram of AD7839 Output Stage

# Power-On with CLR Low

The output stage of the AD7839 has been designed to allow output stability during power-on. If  $\overline{CLR}$  is kept low during power-on, then just after power is applied to the AD7839, the situation is as depicted in Figure 14.  $G_1$ ,  $G_4$  and  $G_6$  are open while  $G_2$ ,  $G_3$  and  $G_5$  are closed.

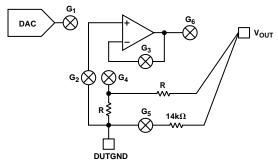


Figure 14. Output Stage with  $V_{DD}$  < 7 V or  $V_{SS}$  > -3 V;  $\overline{CLR}$  Low

 $V_{OUT}$  is kept within a few hundred millivolts of DUTGND via  $G_5$  and a 14 k $\Omega$  resistor. This thin-film resistor is connected in parallel with the gain resistors of the output amplifier. The output amplifier is connected as a unity gain buffer via  $G_3$ , and the DUTGND voltage is applied to the buffer input via  $G_2$ . The amplifier's output is thus at the same voltage as the DUTGND pin. The output stage remains configured as in Figure 14 until the voltage at  $V_{DD}$  exceeds 7 V and  $V_{SS}$  is more negative than -3 V. By now the output amplifier has enough headroom to handle signals at its input and has also had time to settle. The internal power-on circuitry opens  $G_3$  and  $G_5$  and closes  $G_4$  and  $G_6$ . This situation is shown in Figure 15. Now the output amplifier is configured in its noise gain configuration via  $G_4$  and  $G_6$ . The DUTGND voltage is still connected to the noninverting input via  $G_2$  and this voltage appears at  $V_{OUT}$ .

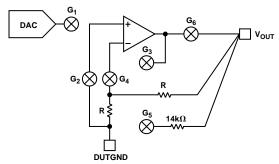


Figure 15. Output Stage with  $V_{DD} > 7$  V and  $V_{SS} < -3$  V;  $\overline{CLR}$  Low

V<sub>OUT</sub> has been disconnected from the DUTGND pin by the opening of G<sub>5</sub>, but will track the voltage present at DUTGND via the configuration shown in Figure 15.

When  $\overline{\text{CLR}}$  is taken back high, the output stage is configured as shown in Figure 16. The internal control logic closes  $G_1$  and opens  $G_2$ . The output amplifier is connected in a noninverting gain-of-two configuration. The voltage that appears on the  $V_{\text{OUT}}$  pins is determined by the data present in the DAC registers.

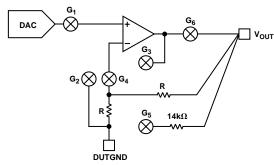


Figure 16. Output Stage After CLR Is Taken High

# Power-On with CLR High

If  $\overline{\text{CLR}}$  is high on the application of power to the device, the output stages of the AD7839 are configured as in Figure 17 while  $V_{DD}$  is less than 7 V and  $V_{SS}$  is more positive than -3 V.  $G_1$  is closed and  $G_2$  is open, thereby connecting the output of the DAC to the input of its output amplifier.  $G_3$  and  $G_5$  are closed while  $G_4$  and  $G_6$  are open, thus connecting the output amplifier as a unity gain buffer.  $V_{OUT}$  is connected to DUTGND via  $G_5$  through a 14 k $\Omega$  resistor until  $V_{DD}$  exceeds 7 V and  $V_{SS}$  is more negative than -3 V.

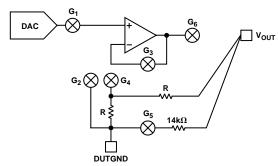


Figure 17. Output Stage Powering Up with  $\overline{CLR}$  High While  $V_{DD} < 7 \text{ V or } V_{SS} > -3 \text{ V}$ 

When the difference between the supply voltages reaches +10 V, the internal power-on circuitry opens  $G_3$  and  $G_5$  and closes  $G_4$  and  $G_6$  configuring the output stage as shown in Figure 18.

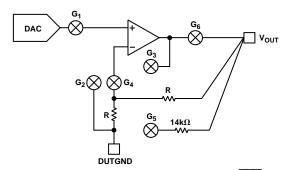


Figure 18. Output Stage Powering Up with  $\overline{CLR}$  High;  $V_{DD} > 7 V$  and  $V_{SS} < -3 V$ 

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# **DUTGND Voltage Range**

During power-on, the  $V_{OUT}$  pins of the AD7839 are connected to the relevant DUTGND pins via  $G_5$  and the 14  $k\Omega$  thin-film resistor. The DUTGND potential must obey the max ratings at all times. Thus, the voltage at DUTGND must always be within the range  $V_{SS}-0.3~V,\,V_{DD}+0.3~V.$  However, in order that the voltages at the  $V_{OUT}$  pins of the AD7839 stay within  $\pm 2~V$  of the relevant DUTGND potential during power-on, the voltage applied to DUTGND should also be kept within the range  $GND-2~V,\,GND+2~V.$ 

Once the AD7839 has powered on and the on-chip amplifiers have settled, any voltage that is now applied to the DUTGND pin is subtracted from the DAC output, which has been gained up by a factor of two. Thus, for specified operation, the maximum voltage that can be applied to the DUTGND pin increases to the maximum allowable 2  $V_{\rm REF}(+)$  voltage, and the minimum voltage that can be applied to DUTGND is the minimum 2  $V_{\rm REF}(-)$  voltage. After the AD7839 has fully powered on, the outputs can track any DUTGND voltage within this minimum/maximum range.

# **Power Supply Sequencing**

When operating the AD7839, it is important that ground be connected at all times to avoid high current states. The recommended power-up sequence is  $V_{\rm DD}/V_{\rm SS}$  followed by  $V_{\rm CC}.$  If  $V_{\rm CC}$  can exceed  $V_{\rm DD}$  on power-up, the diode scheme shown in the absolute max ratings will ensure protection. The reference inputs and digital inputs should be powered up last. Should the references exceed  $V_{\rm DD}/V_{\rm SS}$  on power-up, current limiting resistors should be inserted in series with the reference inputs to limit the current to 20 mA. Logic inputs should not be applied before  $V_{\rm CC}.$  Current limiting resistors (470  $\Omega$ ), in series with the logic inputs, should be inserted if these inputs come up before  $V_{\rm CC}.$ 

# MICROPROCESSOR INTERFACING Interfacing the AD7839—16-Bit Interface

The AD7839 can be interfaced to a variety of 16-bit microcontrollers or DSP processors. Figure 19 shows the AD7839 interfaced to a generic 16-bit microcontroller/DSP processor. The lower address lines from the processor are connected to A0, A1 and A2 on the AD7839 as shown. The upper address lines are decoded to provide a chip select signal or an  $\overline{\text{LDAC}}$  signal for the AD7839. The fast interface timing of the AD7839 allows direct interface to a wide variety of microcontrollers and DSPs as shown in Figure 19.

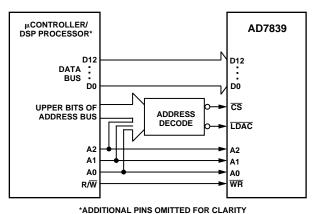


Figure 19. AD7839 Parallel Interface

### APPLICATIONS

# Power Supply Bypassing and Grounding

In any circuit where accuracy is important, careful consideration of the power supply and ground return layout helps to ensure the rated performance. The printed circuit board on which the AD7839 is mounted should be designed such that the analog and digital sections are separated and confined to certain areas of the board. This facilitates the use of ground planes that can be easily separated. A minimum etch technique is generally best for ground planes as it gives the best shielding. Digital and analog ground planes should be joined at only one place. The GND pin of the AD7839 should be connected to the AGND of the system. If the AD7839 is in a system where multiple devices require an AGND-to-DGND connection, the connection should be made at one point only, a star ground point that should be established as close as possible to the AD7839.

Digital lines running under the device should be avoided as these will couple noise onto the die. The analog ground plane should be allowed to run under the AD7839 to avoid noise coupling. The power supply lines of the AD7839 should use as large a trace as possible to provide low impedance paths and reduce the effects of glitches on the power supply line. Fast switching signals like clocks should be shielded with digital ground to avoid radiating noise to other parts of the board and should never be run near the analog inputs.

Avoid crossover of digital and analog signals. Traces on opposite sides of the board should run at right angles to each other. This reduces the effects of feedthrough through the board. A microstrip technique is by far the best but not always possible with a double sided board. In this technique, the component side of the board is dedicated to ground plane while signal traces are placed on the solder side.

The AD7839 should have ample supply bypassing located as close to the package as possible, ideally right up against the device. Figure 20 shows the recommended capacitor values of  $10~\mu F$  in parallel with  $0.1~\mu F$  on each of the supplies. The  $10~\mu F$  capacitors are the tantalum bead type. The  $0.1~\mu F$  capacitor should have low Effective Series Resistance (ESR) and Effective Series Inductance (ESI), such as the common ceramic types, which provide a low impedance path to ground at high frequencies to handle transient currents due to internal logic switching.

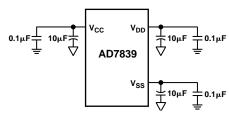


Figure 20. Recommended Decoupling Scheme for AD7839

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# **Automated Test Equipment**

The AD7839 is particularly suited for use in an automated test environment. Figure 21 shows the AD7839 providing the necessary voltages for the pin driver and the window comparator in a typical ATE pin electronics configuration. AD588s are used to provide reference voltages for the AD7839. In the configuration shown, the AD588s are configured so that the voltage at Pin 1 is 5 V greater than the voltage at Pin 9 and the voltage at Pin 15 is 5 V less than the voltage at Pin 9.

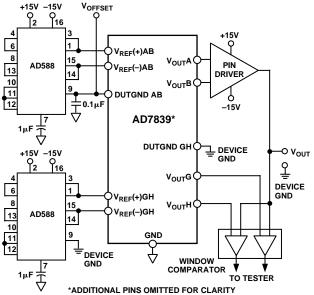


Figure 21. ATE Application

One of the AD588s is used as a reference for DACs A and B. These DACs are used to provide high and low levels for the pin driver. The pin driver may have an associated offset. This can be nulled by applying an offset voltage to Pin 9 of the AD588. First, the code  $1000\ldots0000$  is loaded into the DACA latch and the pin driver output is set to the DACA output. The  $V_{OFFSET}$  voltage is adjusted until 0 V appears between the pin driver output and DUT GND. This causes both  $V_{REF}(+)$  and  $V_{REF}(-)$  to be offset with respect to GND by an amount equal to  $V_{OFFSET}$ . However, the output of the pin driver will vary from -10~V to +10~V with respect to DUTGND as the DAC input code varies from  $000\ldots000$  to  $111\ldots111$ . The  $V_{OFFSET}$  voltage is also applied to the DUTGND pins. When a clear is performed on the AD7839, the output of the pin driver will be 0~V with respect to DUTGND.

The other AD588 is used to provide a reference voltage for DACs G and H. These provide the reference voltages for the window comparator shown in the diagram. Note that Pin 9 of this AD588 is connected to Device GND. This causes  $V_{REF}(+)GH$  and  $V_{REF}(-)GH$  to be referenced to Device GND. As DAC G and DAC H input codes vary from  $000\ldots000$  to  $111\ldots111$ ,  $V_{OUT}G$  and  $V_{OUT}H$  vary from -10 V to +10 V with respect to Device GND. Device GND is also connected to DUTGND. When the AD7839 is cleared,  $V_{OUT}G$  and  $V_{OUT}H$  are cleared to 0 V with respect to Device GND.

# Programmable Reference Generation for the AD7839 in an ATE Application

The AD7839 is particularly suited for use in an automated test environment. The reference input for the AD7839 octal 13-bit DAC requires three differential references for the eight DACs. Programmable references may be a requirement in some ATE applications as the offset and gain errors at the output of a DAC can be adjusted by varying the voltages on the reference pins of the DAC. To trim offset errors, the DAC is loaded with the digital code  $000\ldots000$  and the voltage on the  $V_{REF}(-)$  pin is adjusted until the desired negative output voltage is obtained. To trim out gain errors, first the offset error is trimmed. Then the DAC is loaded with the code  $111\ldots111$  and the voltage on the  $V_{REF}(+)$  pin is adjusted until the desired full-scale voltage minus one LSB is obtained.

It is not uncommon in ATE design, to have other circuitry at the output of the AD7839 that can have offset and gain errors of up to say  $\pm 300$  mV. These offset and gain errors can be easily removed by adjusting the reference voltages of the AD7839. The AD7839 uses nominal reference values of  $\pm 5$  V to achieve an output span of  $\pm 10$  V. Since the AD7839 has a gain of two from the reference inputs to the DAC output, adjusting the reference voltages by  $\pm 150$  mV will adjust the DAC offset and gain by  $\pm 300$  mV.

There are a number of suitable 8- and 10-bit DACs available that would be suitable to drive the reference inputs of the AD7839, such as the AD7804, a quad 10-bit digital-to-analog converter with serial load capabilities. The voltage output from this DAC is in the form of  $V_{\rm BIAS} \pm V_{\rm SWING}$  and rail-to-rail operation is achievable. The voltage reference for this DAC can be internally generated or provided externally. This DAC also contains an 8-bit SUB DAC which can be used to shift the complete transfer function of each DAC around the  $V_{\rm BIAS}$  point. This can be used as a fine trim on the output voltage. In this application two AD7804s are required to provide programmable reference capability for all eight DACs. One AD7804 is used to drive the  $V_{\rm REF}(+)$  pins and the second package used to drive the  $V_{\rm REF}(-)$  pins.

Another suitable DAC for providing programmable reference capability is the AD8803. This is an octal 8-bit trimDAC® and provides independent control of both the top and bottom ends of the trimDAC. This is helpful in maximizing the resolution of devices with a limited allowable voltage control range.

The AD8803 has an output voltage range of GND to  $V_{DD}$  (0 V to +5 V). To trim the  $V_{REF}(+)$  input, the appropriate trim range on the AD8803 DAC can be set using the  $V_{REFL}$  and  $V_{REFH}$  pins allowing 8 bits of resolution between the two points. This will allow the  $V_{REF}(+)$  pin to be adjusted to remove gain errors.

To trim the  $V_{REF}(-)$  voltage, some method of providing a trim voltage in the required negative voltage range is required. Neither the AD7804 or the AD8803 can provide this range in normal operation as their output range is 0 V to +5 V. There are two methods of producing this negative voltage. One method is to provide a positive output voltage and then to level shift that analog voltage to the required negative range. Alternatively

these DACs can be operated with supplies of 0 V and –5 V, with the  $V_{\rm DD}$  pin connected to 0 V and the GND pin connected to –5 V. Now these can be used to provide the negative reference voltages for the  $V_{\rm REF}(-)$  inputs on the AD7839. However, the

digital signals driving the DACs need to be level-shifted from the 0 V to +5 V range to the -5 V to 0 V range. Figure 22 shows a typical application circuit to provide programmable reference capabilities for the AD7839.

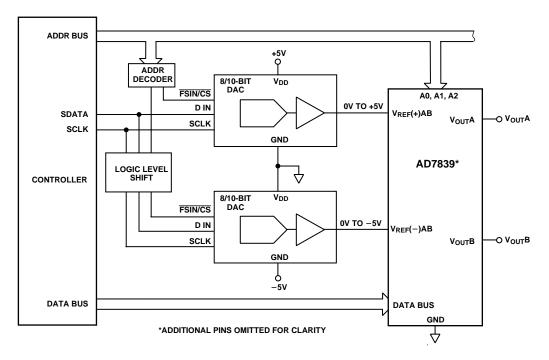
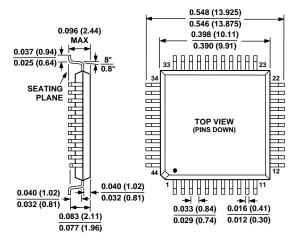


Figure 22. Programmable Reference Generation for the AD7839

# **OUTLINE DIMENSIONS**

Dimensions shown in inches and (mm).

# 44-Lead MQFP (S-44)



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